

Micro Commercial Components 20736 Marilla Street Chatsworth

CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939

SI2301

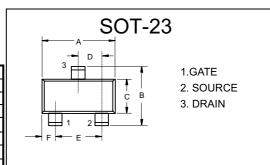
Features

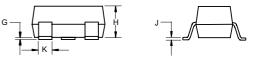
- -20V,-2.8A, $R_{DS(ON)}$ =120m Ω @ V_{GS} =-4.5V $R_{DS(ON)}$ =150m Ω @V_{GS}=-2.5V
- High dense cell design for extremely low R_{DS(ON)}
- Rugged and reliable
- High Speed Switching
- SOT-23 Package
- Marking Code: S1
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0

Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-source Voltage	-20	V
I _D	Drain Current-Continuous	-2.8	Α
I_{DM}	Drain Current-Pulsed ^a	-10	Α
V_{GS}	Gate-source Voltage	±8	V
P_{D}	Total Power Dissipation	1.25	W
R ₀ JA	Thermal Resistance Junction to Ambient ^b	100	°C/W
TJ	Operating Junction Temperature	-55 to +150	$^{\circ}$
T _{STG}	Storage Temperature	-55 to +150	$^{\circ}\!\mathbb{C}$

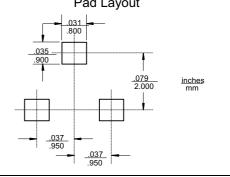
P-Channel Enhancement Mode Field Effect Transistor



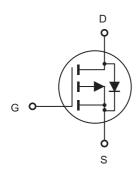


DIMENSIONS								
	INCHES		MM					
DIM	MIN	MAX	MIN	MAX	NOTE			
Α	.110	.120	2.80	3.04				
В	.083	.098	2.10	2.64				
С	.047	.055	1.20	1.40				
D	.035	.041	.89	1.03				
Е	.070	.081	1.78	2.05				
F	.018	.024	.45	.60				
G	.0005	.0039	.013	.100				
Н	.035	.044	.89	1.12				
J	.003	.007	.085	.180				
K	.015	.020	.37	.51				

Suggested Solder Pad Layout



Internal Block Diagram





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Electrical Characteristics T_A = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min	Тур	Max	Units				
Off Characteristics										
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS} = 0V, I_{D} = -250\mu A$	-20			V				
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -20V, V _{GS} = 0V			-1	μΑ				
Gate Body Leakage Current, Forward	I _{GSSF}	$V_{GS} = 8V, V_{DS} = 0V$			100	nA				
Gate Body Leakage Current, Reverse	Igssr	V_{GS} = -8V, V_{DS} = 0V			-100	nA				
On Characteristics °										
Gate Threshold Voltage	V _{GS(th)}	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.45			V				
Static Drain-Source		$V_{GS} = -4.5V, I_{D} = -2.8A$		80	120	mΩ				
On-Resistance	R _{DS(on)}	$V_{GS} = -2.5V, I_{D} = -2.0A$		110	150	mΩ				
Forward Transconductance	9 _{FS}	$V_{DS} = -5V, I_{D} = -2.8A$		8		S				
Dynamic Characteristics d										
Input Capacitance	C _{iss}	.,		880		pF				
Output Capacitance	C _{oss}	$V_{DS} = -6V, V_{GS} = 0V,$ f = 1.0 MHz		270		pF				
Reverse Transfer Capacitance	C _{rss}			175		pF				
Switching Characteristics d										
Turn-On Delay Time	t _{d(on)}			11	20	ns				
Turn-On Rise Time	t _r	$V_{DD} = -6V, I_{D} = -1A,$		5	10	ns				
Turn-Off Delay Time	t _{d(off)}	$V_{GS} = -4.5V$, $R_{GEN} = 6\Omega$		32	65	ns				
Turn-Off Fall Time	t _f			23	45	ns				
Total Gate Charge	Qg	\/ O\/ O O A		11	14.5	nC				
Gate-Source Charge	Q _{gs}	$V_{DS} = -6V, I_{D} = -2.8A,$ $V_{GS} = -4.5V$		1.5		nC				
Gate-Drain Charge	Q _{gd}	- VGS 1.0V		2.1		nC				
Drain-Source Diode Characteristics and Maximun Ratings										
Drain-Source Diode Forward Current b	I _S				-0.75	А				
Drain-Source Diode Forward Voltage c	V _{SD}	$V_{GS} = 0V, I_{S} = -0.75A$			-1.2	V				

Notes:
a.Repetitive Rating: Pulse width limited by maximum junction temperature.b.Surface Mounted on FR4 Board, t < 5 sec.
c.Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
d.Guaranteed by design, not subject to production testing.



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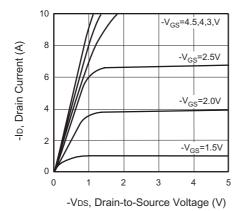


Figure 1. Output Characteristics

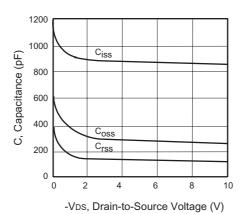


Figure 3. Capacitance

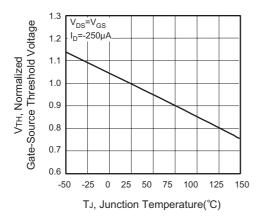


Figure 5. Gate Threshold Variation with Temperature

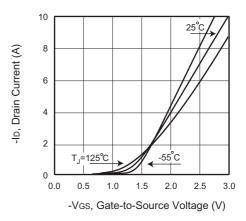


Figure 2. Transfer Characteristics

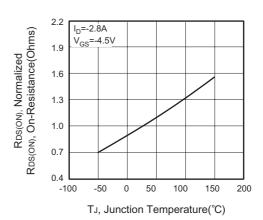


Figure 4. On-Resistance Variation with Temperature

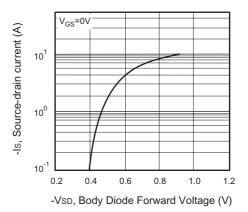


Figure 6. Body Diode Forward Voltage Variation with Source Current



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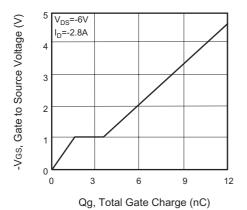


Figure 7. Gate Charge

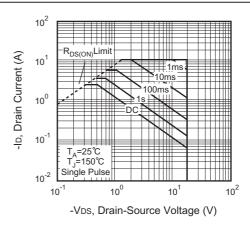


Figure 8. Maximum Safe Operating Area

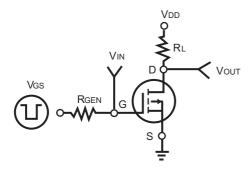


Figure 9. Switching Test Circuit

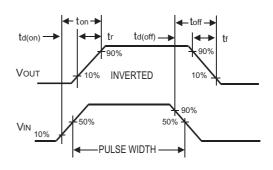


Figure 10. Switching Waveforms

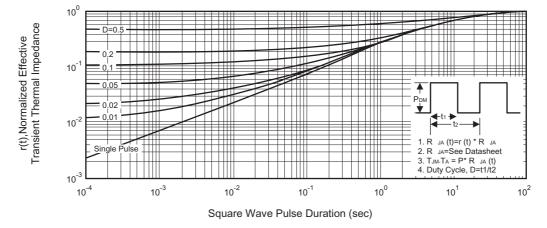


Figure 11. Normalized Thermal Transient Impedance Curve



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